



12V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- BV_{CEO} > -12V
- I_C = 3A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- $R_{CE(sat)} = 65m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-100mV max @ 1A)
- h_{EE} Characterized up to -10A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

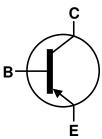
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 (3)
- Weight: 0.015 grams (Approximate)

Applications

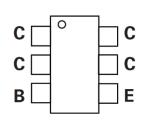
- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control







Device Symbol



Pin-Out Top

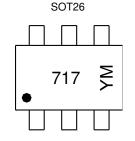
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P12DE6TA	717	7	8	3,000
ZXT10P12DE6TC	717	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



717 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	2	016	2017	2018	2019	2020	202	1 20	22 2	2023	2024	2025
Code	С		D	Е	F	G	Н		,	J	K	L	М
Month	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	N	D





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-12	V
Collector-Emitter Voltage	V _{CEO}	-12	V
Emitter-Base Voltage	V _{EBO}	-7	V
Base Current	I _B	-500	mA
Continuous Collector Current	Ic	-3	Α
Peak Pulse Collector Current	Ісм	-10	Α

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D.	1.1 8.8	W mW/°C	
Linear Derating Factor	(Note 6)	P _D	1.7 13.6		
Thermal Decistance, Junction to Ambient	(Note 5)	В	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$-$ R _{θJA}	73	*G/ VV	
Thermal Resistance, Junction to Leads	$R_{ heta JL}$	30.0	°C/W		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

^{6.} Same as Note 5, except the device is measured at $t \le 5$ seconds.

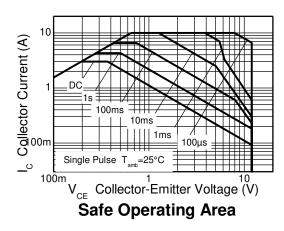
^{7.} Thermal resistance from junction to solder-point (at the end of the collector leads).

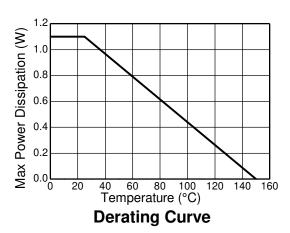
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

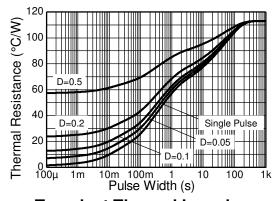




Thermal Characteristics and Derating Information







Transient Thermal Impedance



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

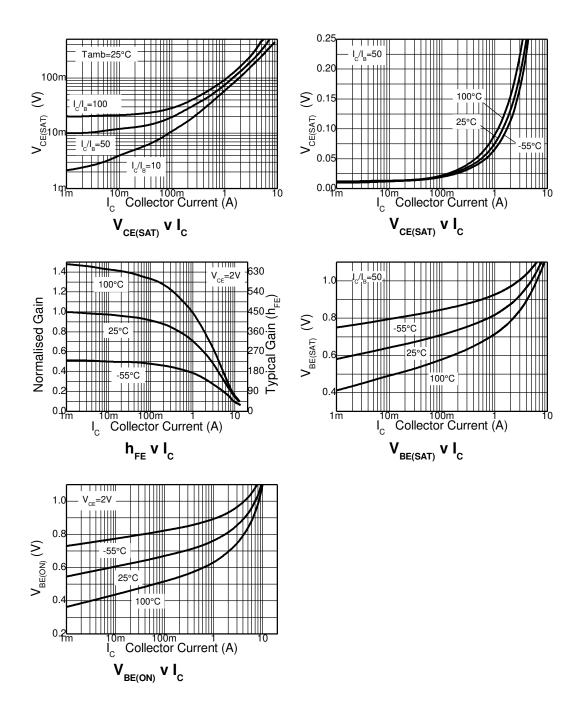
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	-12	-35	_	V	$I_C = -100\mu A$	
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-12	-25		V	I _C = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.5	_	V	$I_E = -100\mu A$	
Collector-Base Cutoff Current	I _{CBO}		<1	-100	nA	V _{CB} = -10V	
Emitter Cutoff Current	I _{EBO}	_	<1	-100	nA	V _{EB} = -4V	
Collector-Emitter Cutoff Current	I _{CES}	_	<1	-100	nA	V _{CES} = -10V	
ON CHARACTERISTICS (Note 9)							
		300	475		_	$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$	
		300	450		_	$I_C = -0.1A, V_{CE} = -2V$	
DC Current Gain (Note 9)	h _{FE}	180	275		_	$I_C = -2.5A, V_{CE} = -2V$	
		60	100	_	_	$I_C = -8.0A$, $V_{CE} = -2V$	
		45	70	_	_	$I_{C} = -10A$, $V_{CE} = -2V$	
		_	-10	-17		I _C = -0.1A, I _B = -10mA	
Collector-Emitter Saturation Voltage (Note 9)	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	_	-100	-140	mV	I _C = -1.0A, I _B = -10mA	
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	-100	-150	111 V	I _C = -1.5A, I _B = -50mA	
		_	-195	-300		I _C = -3.0A, I _B = -50mA	
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	-0.90	-0.95	V	I _C = -3.0A, I _B = -50mA	
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	-0.85	-0.90	V	I _C = -3.0A, V _{CE} = -2V	
SMALL SIGNAL CHARACTERISTICS							
Current Gain-Bandwidth Product	f _T	80	110	_	MHz	$V_{CE} = -10V$, $I_{C} = -50mA$, $f = 100MHz$	
Output Capacitance	C _{obo}	_	21	30	pF	V _{CB} = -10V, f = 1MHz	
Turn-On Time	t _(on)	_	70	_	ns	V _{CC} = -6V, I _C = -2A	
Turn-Off Time	t _(off)	_	130	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$	

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.





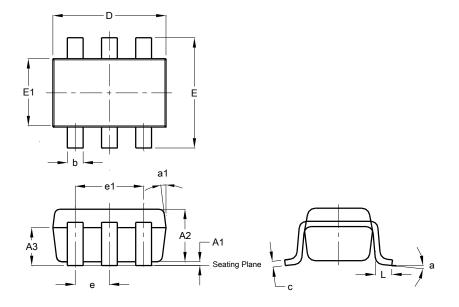
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

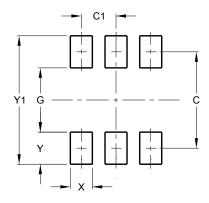
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26						
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
A3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	-	0.95			
e1	-	-	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	-	8°			
a1	-	-	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20





March 2015

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